

10 MHz Operational Amplifier with EMI Filtering

Features

- Low Quiescent Current:
 - 720 µA (maximum)/amplifier
- Low Input Offset Voltage:
 - ±1.6 mV (maximum)
- Enhanced EMI Protection
- Supply Voltage Range: 1.8V to 5.5V
- Gain Bandwidth Product: 10 MHz (typical)
- Rail-to-Rail Input/Output
- Unity Gain Stable
- No Phase Reversal
- Quick Start-up Time
- Small Packages:
 - Singles in SC70-5, SOT-23-5
 - Dual in SOIC-8, MSOP-8
 - Quad in SOIC-14, TSSOP-14
- Extended Temperature Range:-40°C to +125°C
- AEC Q100 Qualified, see Section "Product Identification System (Automotive)"

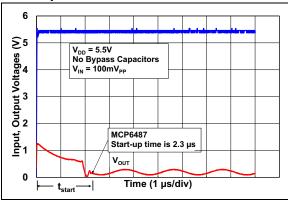
Applications

- Automotive
- Portable Equipment
- Medical Diagnostic Equipment
- Active Filters
- Sensor Conditioning

Design Aids

- SPICE Macro Models
- Microchip Advanced Part Selector (MAPS)
- · Analog Demonstration and Evaluation Boards
- Application Notes

Start-Up Time

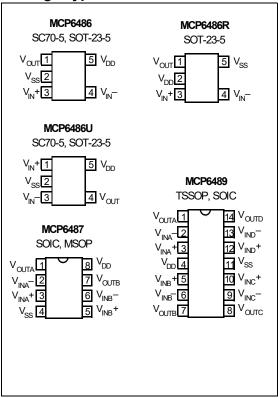


Description

The Microchip Technology Inc. MCP6486/6R/6U/7/9 Operational Amplifier operates with a single-supply voltage, as low as 1.8V, while drawing low-quiescent current (720 μ A, maximum per amplifier). This op amp also has low-input offset voltage (±1.6 mV, maximum) and rail-to-rail input and output operation. In addition, the MCP6486/6R/6U/7/9 is unity gain stable and has a gain bandwidth product of 10 MHz (typical).

The MCP6486/6R/6U/7/9 has EMI protection to minimize the effects of electromagnetic interference from external sources. This feature makes it suited for EMI sensitive applications such as power lines, radio stations and mobile communications.

This family is offered in single (MCP6486), dual (MCP6487) and quad (MCP6489) packages. All devices are designed using an advanced CMOS process and fully specified in the extended temperature range from -40° C to $+125^{\circ}$ C.



Package Types

1.0 ELECTRICAL CHARACTERISTICS

1.1 Absolute Maximum Ratings[†]

$V_{DD} - V_{SS}$	6V
Current at Analog Input Pins (V _{IN} +, V _{IN} -)	±5 mA
Analog Inputs (V _{IN} +, V _{IN} -) ^{††}	V_{SS} – 0.5V to V_{DD} + 0.5V
Analog Ouputs (V _{OUT})	V_{SS} - 0.3V to V_{DD} + 0.3V
Difference Input Voltage	V _{DD} – V _{SS}
Output Short-Circuit Current (Note 1)	Continuous
Storage Temperature	65°C to +150°C
Maximum Junction Temperature (T _J)	+150°C
ESD Protection on All Pins (HBM; CDM; MM)	≥ 4 kV; 2 kV; 200V

Note 1: Short-circuit to ground, one amplifier per package

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

†† See Section 4.1.2 "Input Voltage Limits".

1.2 Specifications

DC Electrical Specifications

Electrical Characteristics : Unless $V_{OUT} = V_{DD}/2$, $V_L = V_{DD}/2$, $R_L = 10$				_{DD} = +1.8V t	o +5.5V,	V_{SS} = GND, V_{CM} = $V_{DD}/4$,
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Input Offset						
Input Offset Voltage	V _{OS}	-1.6		1.6	mV	
Input Offset Drift with Temperature	$\Delta V_{OS} / \Delta T_A$	_	±0.6	_	µV/°C	T _A = -40°C to +125°C
Power Supply Rejection Ratio	PSRR	82	100	—	dB	
Input Bias Current and Impedan	се					
Input Bias Current	Ι _Β	—	±1	—	pА	
		—	19	—	pА	T _A = +85°C
		—	200	—	pА	T _A = +125°C
Input Offset Current	I _{OS}	—	±1	—	pА	
Common Mode Input Impedance	Z _{CM}	—	10 ¹³ 6	—	Ω∥pF	
Differential Input Impedance	Z _{DIFF}	—	10 ¹³ 2	—	Ω∥pF	
Common Mode						
Common Mode Input Voltage	V _{CMR}	$V_{SS} - 0.3$	_	V _{DD} + 0.3	V	
Range		V _{SS} – 0.1	_	V _{DD} + 0.1		T _A = -40°C to +125°C, Guaranteed by Characterization.
Common Mode Rejection Ratio	CMRR	—	125	_	dB	V _{DD} = 5.5V V _{CM} = -0.1V to 4.1V
		66	110		dB	V _{DD} = 5.5V V _{CM} = -0.3V to 5.8V
			75		dB	V _{DD} = 1.8V V _{CM} = -0.3V to 2.1V

DC Electrical Specifications (Continued)

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Open-Loop Gain						I
DC Open-Loop Gain (Large Signal)	A _{OL}	105	130	_	dB	0.2 < V _{OUT} < (V _{DD} -0.2V)
Output	•		•			
High-Level Output Voltage	V _{OH}	V _{DD} – 10	$V_{DD} - 3.5$	_	mV	V _{DD} = 5.5V, R _L = 10 kΩ
		V _{DD} - 50	V _{DD} - 30	_		V_{DD} = 5.5V, R _L = 1 kΩ
Low-Level Output Voltage	V _{OL}	—	V _{SS} + 3.5	V _{SS} + 10	mV	V_{DD} = 5.5V, R _L = 10 kΩ
		—	V _{SS} + 30	V _{SS} + 50		V_{DD} = 5.5V, R_L = 1 k Ω
Output Short-Circuit Current	I _{SC}	—	±11	—	mA	V _{DD} = 1.8V
			±50	—	mA	V _{DD} = 5.5V
Power Supply						
Supply Voltage	V _{DD}	1.8	_	5.5	V	
Quiescent Current per Amplifier	ا _Q	—	550	720	μA	I _O = 0
Startup Time	t _{start}	—	2.3	—	μs	V _{DD} = 0V to 5.5V
Crosstalk			135	_	dB	

AC Electrical Specifications

Electrical Characteristics: Unless otherwise indicated, T_A = +25°C, V_{DD} = +1.8V to +5.5V, V_{SS} = GND, V_{CM} = $V_{DD}/4$, V_{OUT} = $V_{DD}/2$, V_L = $V_{DD}/2$, R_L = 10 k Ω to V_L and C_L = 30 pF.

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
AC Response						
Gain Bandwidth Product	GBWP	_	10	_	MHz	
Phase Margin	PM	_	60	_	٥	G = +1 V/V
Slew Rate	SR	—	20	_	V/µs	V _{DD} = 5.5V, V _{IN} > 4V
Settling Time	t _s	_	0.4	—	μs	To 0.1%, V _{DD} = 5V, 2V step, G = +1
		—	0.5	—		To 0.01%, V _{DD} = 5V, 2V step, G = +1
Total Harmonic Distortion + Noise	THD+N	_	0.002	_	%	V_{DD} = 5V, V_o = 1 V_{RMS} , G = +1, f = 1 kHz, 80 kHz measurement BW.
Noise						
Input Noise Voltage	E _{ni}		3.4		μV _{P-P}	f = 0.1 Hz to 10 Hz
Input Noise Voltage Density	e _{ni}	_	16	_	nV/√Hz	f = 1 kHz
		_	10	_	nV/√Hz	f = 10 kHz
Input Noise Current Density	i _{ni}	_	0.6	_	fA/√Hz	f = 1 kHz

AC Electrical Specifications (Continued)

		,				
Electrical Characteristics : Unless otherwise indicated, T_A = +25°C, V_{DD} = +1.8V to +5.5V, V_{SS} = GND, V_{CM} = $V_{DD}/4$, V_{OUT} = $V_{DD}/2$, V_L = $V_{DD}/2$, R_L = 10 k Ω to V_L and C_L = 30 pF.						
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Electromagnetic Interference	EMIRR	—	30	_	dB	V _{IN} = 100 mV _{PK} , 400 MHz
Rejection Ratio		—	45	—		V _{IN} = 100 mV _{PK} , 900 MHz
		—	61	—		V _{IN} = 100 mV _{PK} ,1800 MHz
			82	_		V _{IN} = 100 mV _{PK} , 2400 MHz
		_	100	—		V _{IN} = 100 mV _{PK} , 5800 MHz

TABLE 1-1: TEMPERATURE SPECIFICATIONS

Electrical Characteristics: Unless otherwise indicated, V_{DD} = +1.8V to +5.5V and V_{SS} = GND.						
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Operating Temperature Range	T _A	-40	_	+125	°C	Note 1
Storage Temperature Range	T _A	-65	_	+150	°C	
Thermal Package Resistances						
Thermal Resistance, 5L-SC70	θ_{JA}		331		°C/W	
Thermal Resistance, 5L-SOT-23	θ_{JA}		221	_	°C/W	
Thermal Resistance, 8L-MSOP	θ_{JA}	_	206	_	°C/W	
Thermal Resistance, 8L-SOIC	θ_{JA}		150	_	°C/W	
Thermal Resistance, 14L-TSSOP	θ_{JA}		100	_	°C/W	
Thermal Resistance, 14L-SOIC	θ_{JA}	_	120	_	°C/W	

Note 1: The internal junction temperature (T_J) must not exceed the absolute maximum specification of +150°C.

2.0 TYPICAL PERFORMANCE CURVES

- **Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.
- Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +1.8V to +5.5V, V_{SS} = GND, V_{CM} = $V_{DD}/4$, V_{OUT} = $V_{DD}/2$, V_L = $V_{DD}/2$, R_L = 10 k Ω to V_L and C_L = 30 pF.

2.1 DC Inputs

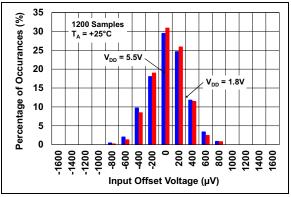
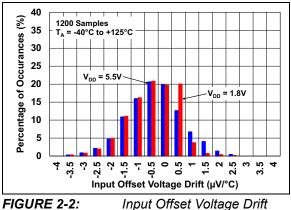
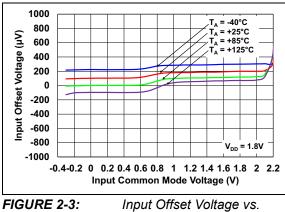


FIGURE 2-1: Input Offset Voltage Histogram.



Histogram.



Common-Mode Input Voltage.

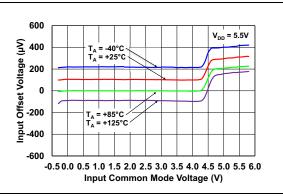


FIGURE 2-4: Input Offset Voltage vs. Common-Mode Input Voltage.

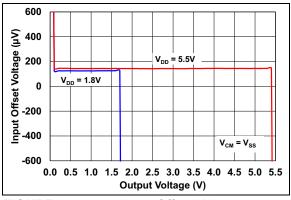
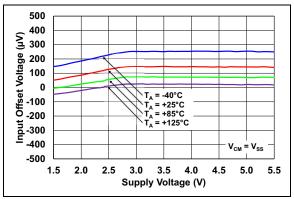
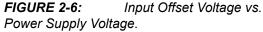


FIGURE 2-5: Input Offset Voltage vs. Output Voltage.





Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +1.8V to +5.5V, V_{SS} = GND, V_{CM} = $V_{DD}/4$, V_{OUT} = $V_{DD}/2$, V_L = $V_{DD}/2$, R_L = 10 k Ω to V_L and C_L = 30 pF.

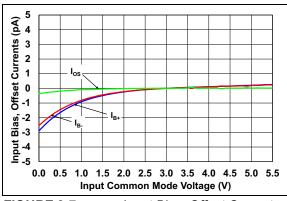


FIGURE 2-7: Input Bias, Offset Current vs. Common-Mode Input Voltage.

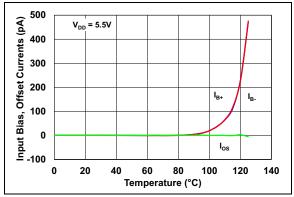


FIGURE 2-8: Input Bias, Offset Currents vs. Temperature.

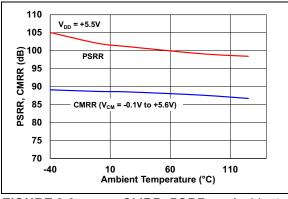


FIGURE 2-9: Temperature.

CMRR, PSRR vs. Ambient

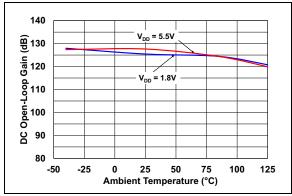


FIGURE 2-10: DC Open-Loop Gain vs. Ambient Temperature.

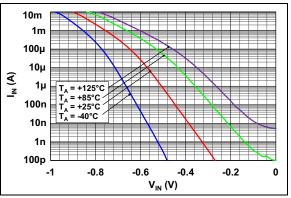


FIGURE 2-11: Measured Input Current vs. Input Voltage (below V_{SS}).

Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +1.8V to +5.5V, V_{SS} = GND, V_{CM} = $V_{DD}/4$, V_{OUT} = $V_{DD}/2$, V_L = $V_{DD}/2$, R_L = 10 k Ω to V_L and C_L = 30 pF.

2.2 Other DC Voltages and Currents

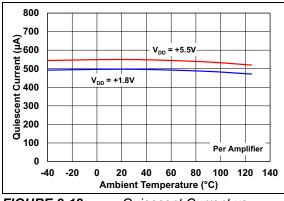


FIGURE 2-12: Quiescent Current vs. Ambient Temperature.

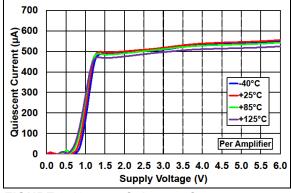


FIGURE 2-13: Quiescent Current vs. Power Supply Voltage.

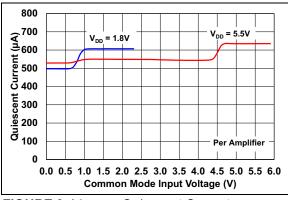


FIGURE 2-14: Quiescent Current vs. Common-Mode Input Voltage.

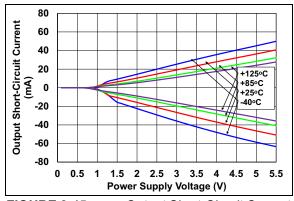


FIGURE 2-15: Output Short-Circuit Current vs. Power Supply Voltage.

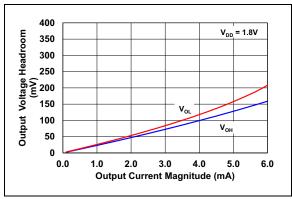
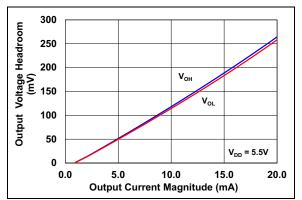
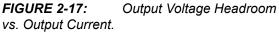


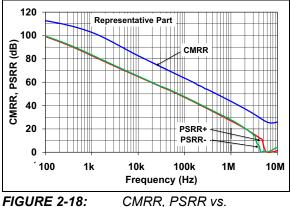
FIGURE 2-16: Output Voltage Headroom vs. Output Current.

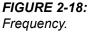




Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +1.8V to +5.5V, V_{SS} = GND, V_{CM} = $V_{DD}/4$, V_{OUT} = $V_{DD}/2$, V_L = $V_{DD}/2$, R_L = 10 k Ω to V_L and C_L = 30 pF.

2.3 Frequency Response





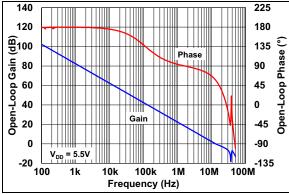


FIGURE 2-19: Open-Loop Gain, Phase vs. Frequency.

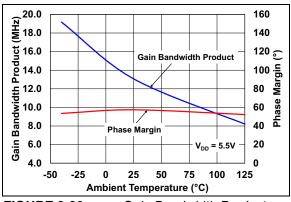


FIGURE 2-20: Gain Bandwidth Product, Phase Margin vs. Ambient Temperature.

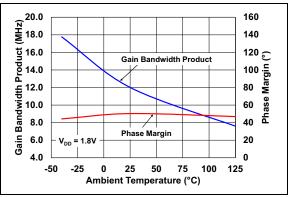


FIGURE 2-21: Gain Bandwidth Product, Phase Margin vs. Ambient Temperature.

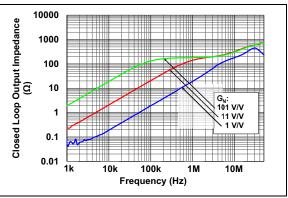
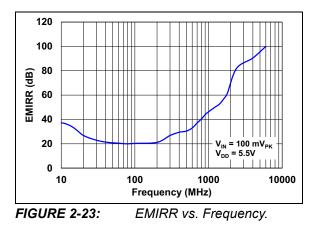


FIGURE 2-22: Closed-Loop Output Impedance vs. Frequency.



Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +1.8V to +5.5V, V_{SS} = GND, V_{CM} = $V_{DD}/4$, V_{OUT} = $V_{DD}/2$, V_L = $V_{DD}/2$, R_L = 10 k Ω to V_L and C_L = 30 pF.

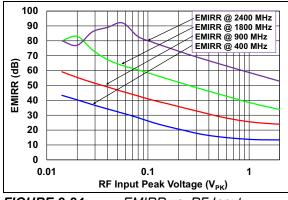


FIGURE 2-24: EMIRR vs. RF Input Peak-to-Peak Voltage.

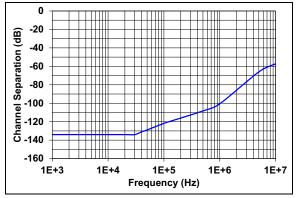


FIGURE 2-25: Channel Separation vs. Frequency.

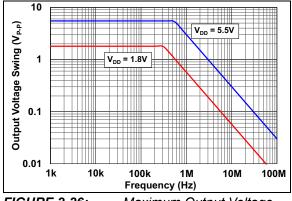


FIGURE 2-26: Maximum Output Voltage Swing vs. Frequency.

Unless otherwise indicated, T_A= +25°C, V_{DD} = +1.8V to +5.5V, V_{SS}= GND, V_{CM} = V_{DD}/4, V_{OUT} = V_{DD}/2, V_L = V_{DD}/2, R_L = 10 k Ω to V_L and C_L = 30 pF. Note:

2.4 **Input Noise**

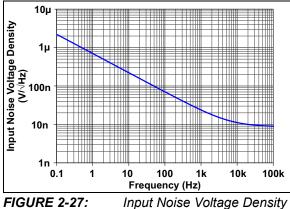


FIGURE 2-27: vs. Frequency.

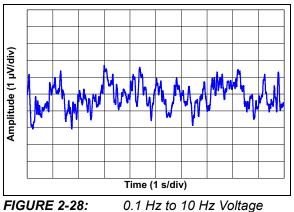


FIGURE 2-28: Noise.

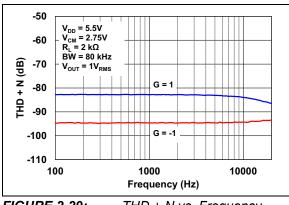
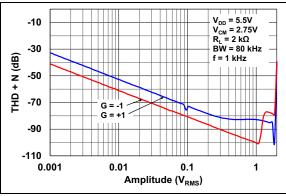
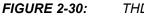


FIGURE 2-29:

THD + N vs. Frequency.





THD + N vs. Amplitude.

Unless otherwise indicated, T_A= +25°C, V_{DD} = +1.8V to +5.5V, V_{SS}= GND, V_{CM} = V_{DD}/4, V_{OUT} = V_{DD}/2, V_L = V_{DD}/2, R_L = 10 k Ω to V_L and C_L = 30 pF. Note:

2.5 **Time Response**

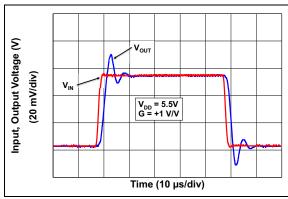


FIGURE 2-31: Small Signal Noninverting Pulse Response.

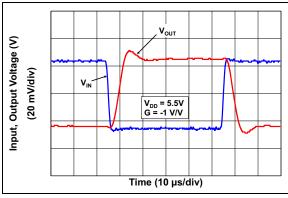
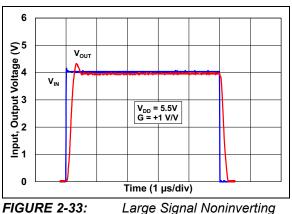


FIGURE 2-32: Response.

Small Signal Inverting Pulse



Pulse Response.

Large Signal Noninverting

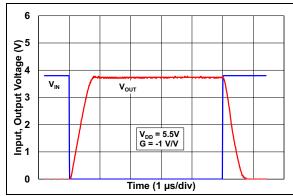
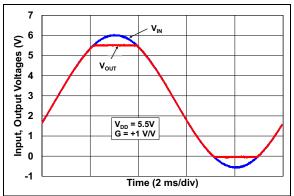
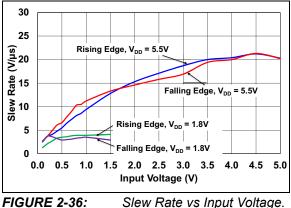


FIGURE 2-34: Response.

Large Signal Inverting Pulse



The MCP6486/6R/6U/7/9 FIGURE 2-35: Device Shows No Phase Reversal.



Slew Rate vs Input Voltage.

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Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +1.8V to +5.5V, V_{SS} = GND, V_{CM} = $V_{DD}/4$, V_{OUT} = $V_{DD}/2$, V_L = $V_{DD}/2$, R_L = 10 k Ω to V_L and C_L = 30 pF.

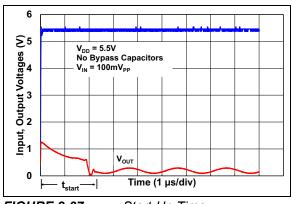


FIGURE 2-37: Start-Up Time.

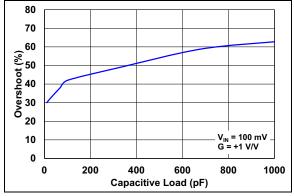


FIGURE 2-38: Overshoot vs. Capacitive Load. (Gain = +1).

3.0 PIN DESCRIPTIONS

Descriptions of the pins are listed in Table 3-1, Table 3-2, and Table 3-3.

TABLE 3-1: PIN FUNCTION TABLE - SINGLES							
MCP6486	MCP6486R	MCP6486U	Symbol	Description			
5-Lead SC70, SOT-23	5-Lead SOT-23	5-Lead SC70, SOT-23	Symbol	Description			
1	1	4	V _{OUT}	Analog Output			
2	5	2	V _{SS}	Negative Power Supply			
3	3	1	V _{IN} +	Noninverting Input			
4	4	3	V _{IN} -	Inverting Input			
5	2	5	V _{DD}	Positive Power Supply			

TABLE 3-1: PIN FUNCTION TABLE - SINGLES

TABLE 3-2: PIN FUNCTION TABLE - DUALS

MCP6487	Symbol	Description
8-Lead MSOP, SOIC	Symbol	Description
1	V _{OUTA}	Analog Output; Op Amp A
2	V _{INA} -	Inverting Input; Op Amp A
3	V _{INA} +	Noninverting Input; Op Amp A
4	V _{SS}	Negative Power Supply
5	V _{INB} +	Noninverting Input; Op Amp B
6	V _{INB} -	Inverting Input; Op Amp B
7	V _{OUTB}	Analog Output; Op Amp B
8	V _{DD}	Positive Power Supply

TABLE 3-3: PIN FUNCTION TABLE - QUADS

MCP6489	Symbol	Description
14-Lead TSSOP, SOIC	Symbol	Description
1	V _{OUTA}	Analog Output; Op Amp A
2	V _{INA} -	Inverting Input; Op Amp A
3	V _{INA} +	Noninverting Input; Op Amp A
4	V _{DD}	Positive Power Supply
5	V _{INB} +	Noninverting Input; Op Amp B
6	V _{INB} -	Inverting Input; Op Amp B
7	V _{OUTB}	Analog Output; Op Amp B
8	V _{OUTC}	Analog Output; Op Amp C
9	V _{INC} -	Inverting Input; Op Amp C
10	V _{INC} +	Noninverting Input; Op Amp C
11	V _{SS}	Negative Power Supply
12	V _{IND} +	Noninverting Input; Op Amp D
13	V _{IND} -	Inverting Input; Op Amp D
14	V _{OUTD}	Analog Output; Op Amp D

3.1 Analog Outputs

The analog output pins (V_{OUTx}) are low-impedance voltage sources.

3.2 Analog Inputs

The noninverting and inverting inputs (V_{INx} +, V_{INx} -) are high-impedance CMOS inputs with low bias currents.

3.3 Power Supply Pins (V_{SS}, V_{DD})

The positive power supply (V_{DD}) is 1.8V to 5.5V higher than the negative power supply (V_{SS}). For normal operation, the other pins are at voltages between V_{SS} and V_{DD}.

Typically, these parts are used in a single (positive) supply configuration. In this case, V_{SS} is connected to ground and V_{DD} is connected to the supply. V_{DD} needs bypass capacitors.

4.0 APPLICATION INFORMATION

The MCP6486/6R/6U/7/9 operational amplifier is unity gain stable and suitable for a wide range of general purpose applications.

4.1 Rail-to-Rail Input

4.1.1 PHASE REVERSAL

The MCP6486/6R/6U/7/9 op amp is designed to prevent phase reversal, when the input pins exceed the supply voltages. Figure 2-35 shows the input voltage exceeding the supply voltage with no phase reversal.

4.1.2 INPUT VOLTAGE LIMITS

In order to prevent damage and/or improper operation of the amplifier, the circuit must limit the voltages at the input pins (see Section 1.1, Absolute Maximum Ratings[†]).

The Electrostatic Discharge (ESD) protection on the inputs can be depicted as shown in Figure 4-1. This structure was chosen to protect the input transistors against many, but not all, overvoltage conditions and to minimize the Input Bias (I_B) current.

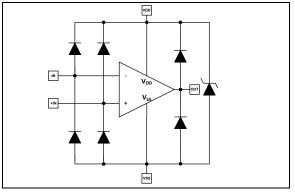


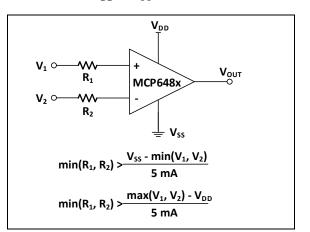
FIGURE 4-1: Simplified Analog Input ESD Structures.

The input ESD diodes clamp the inputs when they try to go more than one diode drop below V_{SS}. They also clamp any voltages that go well above V_{DD}; their breakdown voltage is high enough to allow normal operation. At 0.5V above V_{DD} or below V_{SS}, the input currents are typically less than 5 mA. Very fast ESD events that meet the specifications are limited so that damage does not occur.

4.1.3 INPUT CURRENT LIMITS

In order to prevent damage and/or improper operation of the amplifier, the circuit must limit the currents into the input pins (see Section 1.1, Absolute Maximum Ratings†).

Figure 4-2 shows one approach to protecting these inputs. The resistors R_1 and R_2 limit the possible currents in or out of the input pins through the ESD diodes to either V_{DD} or V_{SS} .





Protecting the Analog

4.1.4 NORMAL OPERATION

The input stage of the MCP6486/6R/6U/7/9 op amp uses two differential input stages in parallel. One operates at a low Common mode input voltage (V_{CM}), while the other operates at a high V_{CM}. With this topology, the device operates with a V_{CM} up to 300 mV above V_{DD} and 300 mV below V_{SS}. The input offset voltage is measured at V_{CM} = V_{SS} - 0.3V and V_{DD} + 0.3V to ensure proper operation.

The transition between the input stages occurs when V_{CM} is near V_{DD} - 0.9V (see Figures 2-3 and 2-4). For the best distortion performance and gain linearity, with noninverting gains, avoid this region of operation.

4.2 Rail-to-Rail Output

The output voltage range of the MCP6486/6R/6U/7/9 op amp is 0.003V (typical) and 5.496V (typical) when $R_L = 10 \text{ k}\Omega$ is connected to $V_{DD}/2$ and $V_{DD} = 5.5V$. Refer to Figures 2-16 and 2-17 for more information.

4.3 Start-up

The MCP6486/6R/6U/7/9 family of parts quickly controls the output when power (V_{DD}) is initially applied to the device (start-up). Bypass capacitors are removed during the start-up testing to minimize the inrush currents (see Figure 4-3). When the op amp is controlled and is off, the output impedance is high and V_{OUT} is the input sine wave; this is used as the start-up time.

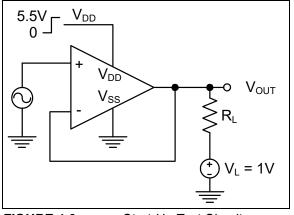


FIGURE 4-3: Start-Up Test Circuit.

Figure 4-4 shows the input voltage (blue line) for the MCP6487 and the output voltage (red line). When power is first applied to the MCP6487, the output is turned off (Point A) and is driven by the load. After 2.3 μ s (typical), the output is turned on (Point B) and V_{OUT} follows the input sine wave.

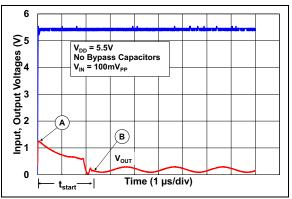


FIGURE 4-4: Start-Up Test Waveforms.

4.4 Capacitive Loads

Driving large capacitive loads can cause stability problems for voltage feedback op amps. As the load capacitance increases, the feedback loop's phase margin decreases, and the closed-loop bandwidth is reduced. This produces gain peaking in the frequency response, with overshoot and ringing in the step response. While a unity-gain buffer (G = +1 V/V) is the most sensitive to the capacitive loads, all gains show the same general behavior.

When driving large capacitive loads with the MCP6486/6R/6U/7/9 op amp, a small series resistor at the output (R_{ISO} in Figure 4-5) improves the feedback loop's phase margin (stability) by making the output load resistive at higher frequencies. The bandwidth will be generally lower than the bandwidth with no capacitance load.

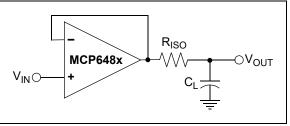


FIGURE 4-5: Output Resistor, R_{ISO} Stabilizes Large Capacitive Loads.

4.5 Supply Bypass

The MCP6486/6R/6U/7/9 op amp's power supply pin (V_{DD} for single-supply) should have a local bypass capacitor (i.e., 0.01 μ F to 0.1 μ F) within 2 mm for good high-frequency performance. It can use a bulk capacitor (i.e., 1 μ F or larger) within 100 mm to provide large, slow currents. This bulk capacitor can be shared with other analog parts.

4.6 PCB Surface Leakage

In applications where low input bias current is critical, the Printed Circuit Board (PCB) surface leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low-humidity conditions, a typical resistance between nearby traces is $10^{12}\Omega$. A 5V difference would cause 5 pA of current to flow, which is greater than the MCP6486/6R/6U/7/9's bias current at +25°C (±1 pA, typical).

The easiest way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. An example of this type of layout is shown in Figure 4-6.

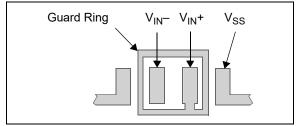


FIGURE 4-6: Example Guard Ring Layout for Inverting Gain.

- 1. Noninverting Gain and Unity-Gain Buffer:
 - a) Connect the noninverting pin (V_{IN}+) to the input with a wire that does not touch the PCB surface.
 - b) Connect the guard ring to the inverting input pin (V_{IN} -). This biases the guard ring to the Common mode input voltage.
- 2. Inverting Gain and Transimpedance Gain Amplifiers (convert current to voltage, such as photo detectors):
 - a) Connect the guard ring to the noninverting input pin (V_{IN}+). This biases the guard ring to the same reference voltage as the op amp (e.g., V_{DD}/2 or ground).
 - b) Connect the inverting pin (V $_{\rm IN}\text{-})$ to the input with a wire that does not touch the PCB surface.

4.7 Unused Op Amps

An unused op amp in a dual (MCP6487) or quad (MCP6489) package should be configured as shown in Figure 4-7. These circuits prevent the output from toggling and causing crosstalk. Circuit A sets the op amp at its minimum noise gain. The resistor divider produces any desired reference voltage within the output voltage range of the op amp; the op amp buffers that reference voltage. Circuit B uses the minimum number of components.

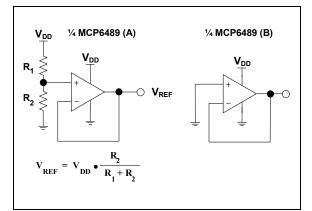


FIGURE 4-7: Unused Op Amps.

4.8 Electromagnetic Interference Rejection Ratio (EMIRR) Definitions

The electromagnetic interference (EMI) is the disturbance that affects an electrical circuit due to either electromagnetic induction or electromagnetic radiation emitted from an external source.

The parameter which describes the EMI robustness of an op amp is the Electromagnetic Interference Rejection Ratio (EMIRR). It quantitatively describes the effect that a Radio Frequency (RF) interfering signal has on op amp performance. Internal passive filters make EMIRR better, compared with older parts. This means that, with good PCB layout techniques, the EMC performance should be better.

EMIRR is defined in Equation 4-1.

EQUATION 4-1:

$$EMIRR(dB) = 20 \times log\left(\frac{V_{RF}}{\Delta V_{OS}}\right)$$

Where:

V_{RF} = Peak Amplitude of RF Interfering Signal (V_{PK})

$$\Delta V_{OS}$$
 = Input Offset Voltage Shift (V)

4.9 Application Circuits

4.9.1 MULTIPLE FEEDBACK LOW-PASS FILTER

The MCP6486/6R/6U/7/9 Op Amp can be used in active-filter applications. Figure 4-8 shows an inverting, third-order, multiple feedback low-pass filter that can be used as an anti-aliasing filter.

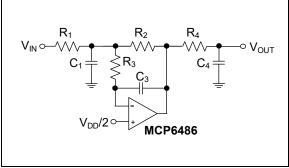


FIGURE 4-8:Multiple FeedbackLow-Pass Filter.

4.9.2 PHOTODIODE AMPLIFIER

Figure 4-9 shows a photodiode biased in the photovoltaic mode for high precision. The resistor R converts the diode current ID to the voltage V_{OUT} . The capacitor is used to limit the bandwidth or to stabilize the circuit against the diode's capacitance.

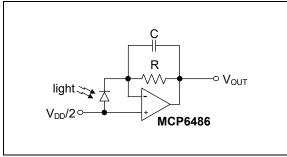


FIGURE 4-9: Photodiode Amplifier.

5.0 DESIGN AIDS

Microchip Technology Inc. provides the basic design tools needed for the MCP6486/6R/6U/7/9 op amp.

5.1 Microchip Advanced Part Selector (MAPS)

MAPS is a software tool that helps semiconductor professionals efficiently identify the Microchip devices that fit a particular design requirement. Available at no cost from the Microchip website at www.microchip.com/maps, MAPS is an overall selection tool for Microchip's product portfolio that includes Analog, Memory, MCUs and DSCs. Using this tool, you can define a filter to sort features for a parametric search of devices and export side-by-side technical comparison reports. Helpful links are also provided for data sheets, purchase and sampling of Microchip parts.

5.2 Analog Demonstration and Evaluation Boards

Microchip offers a broad spectrum of Analog Demonstration and Evaluation Boards that are designed to help you achieve faster time to market. For a complete listing of these boards and their corresponding user's guides and technical information, visit the Microchip web site at www.microchipdirect.com.

Some boards that are especially useful are:

- MCP6XXX Amplifier Evaluation Board 2 (P/N DS51668)
- MCP6XXX Amplifier Evaluation Board 3 (P/N DS51673)
- 8-Pin SOIC/MSOP/TSSOP/DIP Evaluation Board (P/N SOIC8EV)
- 5/6-Pin SOT-23 Evaluation Board (P/N VSUPEV2)
- 14-Pin SOIC/TSSOP/DIP Evaluation Board (P/N SOIC14EV)

5.3 Application Notes

The following Microchip Analog Design Note and Application Notes are available on the Microchip web site at www.microchip.com/appnotes, and are recommended as supplemental reference resources.

- ADN003 "Select the Right Operational Amplifier for your Filtering Circuits", DS21821
- AN722 "Operational Amplifier Topologies and DC Specifications", DS00722
- AN723 "Operational Amplifier AC Specifications and Applications", DS00723
- AN884 "Driving Capacitive Loads With Op Amps", DS00884
- AN990 "Analog Sensor Conditioning Circuits – An Overview", DS00990
- AN1177 "Op Amp Precision Design: DC Errors", DS01177
- AN1228 "Op Amp Precision Design: Random Noise", DS01228
- AN1258 "Op Amp Precision Design: PCB Layout Techniques", DS01258

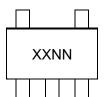
These application notes and others are listed in the design guide:

• "Signal Chain Design Guide", DS21825

6.0 PACKAGING INFORMATION

6.1 Package Marking Information

5-Lead SC70 (**MCP6486/6U**)



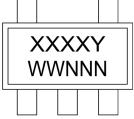
Device	Marking
MCP6486	HANN
MCP6486U	HBNN

Note: Applies to 5-Lead SC-70.

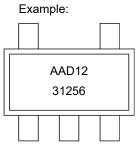
HA74	

Example:

5-Lead SOT-23 (MCP6486/6U/6R)

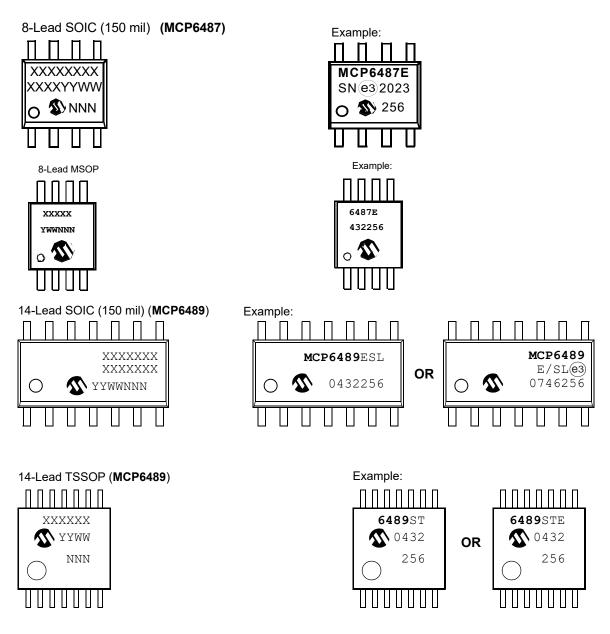


	Device	Marking	
]	MCP6486	AAD1	
	MCP6486U	AAD2	
	MCP6486R	AAD3	
	Note: Applies to 5-Lead SOT-23.		



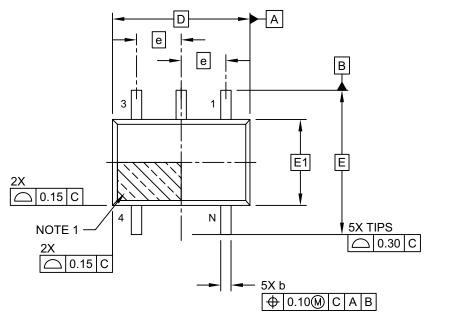
Legen	d: XXX Y YY WW NNN @3 *	Customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.
Note:	be carrie	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for customer-specific information.

Package Marking Information (Continued)

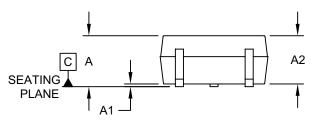


5-Lead Plastic Small Outline Transistor (LT) [SC70]

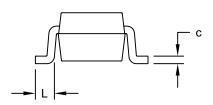
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging







SIDE VIEW

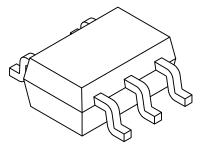


END VIEW

Microchip Technology Drawing C04-061-LT Rev E Sheet 1 of 2

5-Lead Plastic Small Outline Transistor (LT) [SC70]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX
Number of Pins	Ν		5	
Pitch	е		0.65 BSC	
Overall Height	Α	0.80 - 1.10		
Standoff	A1	0.00	-	0.10
Molded Package Thickness	A2	0.80 - 1.00		
Overall Length	D		2.00 BSC	
Overall Width	E		2.10 BSC	
Molded Package Width	E1		1.25 BSC	
Terminal Width	b	0.15 - 0.40		
Terminal Length	L	0.10 0.20 0.46		
Lead Thickness	С	0.08	-	0.26

Notes:

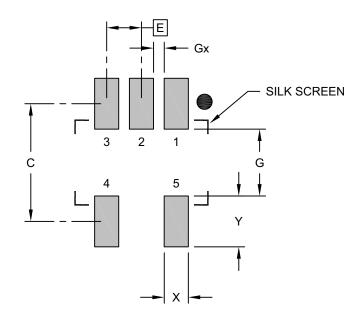
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- 3. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-061-LT Rev E Sheet 2 of 2

5-Lead Plastic Small Outline Transistor (LT) [SC70]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units		MILLIMETERS		
Dimensior	Dimension Limits		NOM	MAX	
Contact Pitch	E	0.65 BSC			
Contact Pad Spacing	С		2.20		
Contact Pad Width	Х			0.45	
Contact Pad Length	Y			0.95	
Distance Between Pads	G	1.25			
Distance Between Pads	Gx	0.20			

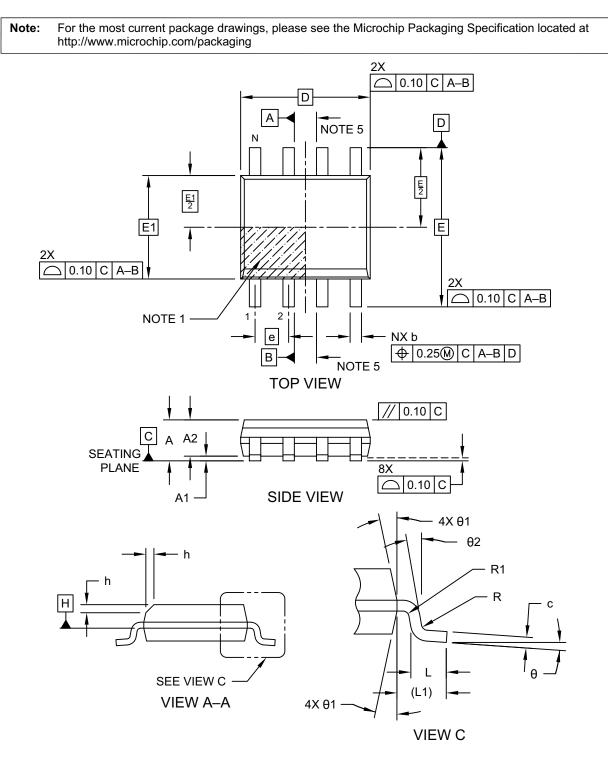
Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2061-LT Rev E

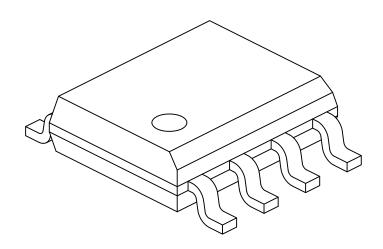
8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]



Microchip Technology Drawing No. C04-057-SN Rev H Sheet 1 of 2

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX
Number of Pins	N	8		
Pitch	е		1.27 BSC	
Overall Height	A	-	_	1.75
Molded Package Thickness	A2	1.25	_	-
Standoff §	A1	0.10	_	0.25
Overall Width	E		6.00 BSC	
Molded Package Width	E1	3.90 BSC		
Overall Length	D	4.90 BSC		
Chamfer (Optional)	h	0.25	_	0.50
Foot Length	L	0.40	_	1.27
Footprint	L1	1.04 REF		
Lead Thickness	С	0.17	_	0.25
Lead Width	b	0.31	-	0.51
Lead Bend Radius	R	0.07	-	-
Lead Bend Radius	R1	0.07	-	_
Foot Angle	θ	0°	-	8°
Mold Draft Angle	θ1	5°	-	15°
Lead Angle	θ2	0°	_	8°

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. § Significant Characteristic

3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.

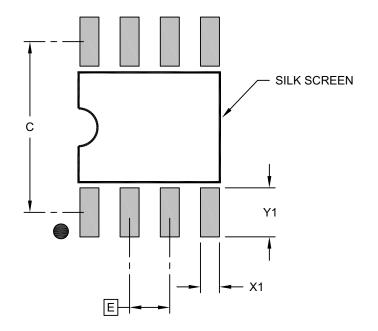
4. Dimensioning and tolerancing per ASME Y14.5M

- BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.
- 5. Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-057-SN Rev H Sheet 2 of 2

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units		MILLIMETERS		
Dimension	Dimension Limits		NOM	MAX	
Contact Pitch	Е	1.27 BSC			
Contact Pad Spacing	С		5.40		
Contact Pad Width (X8)	X1			0.60	
Contact Pad Length (X8)	Y1			1.55	

Notes:

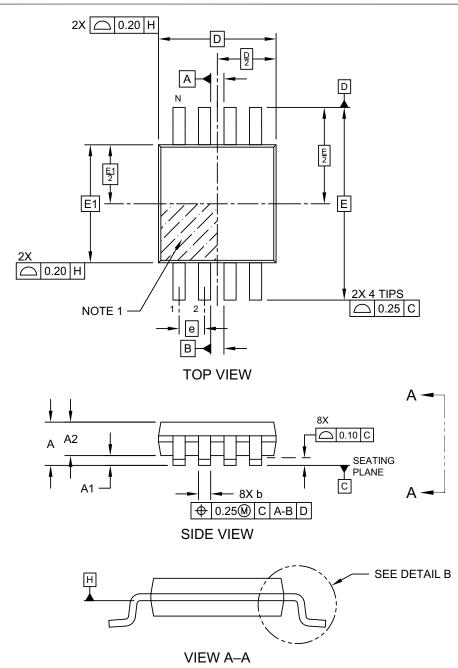
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-2057-SN Rev H

8-Lead Plastic Micro Small Outline Package (MS) - 3x3 mm Body [MSOP]

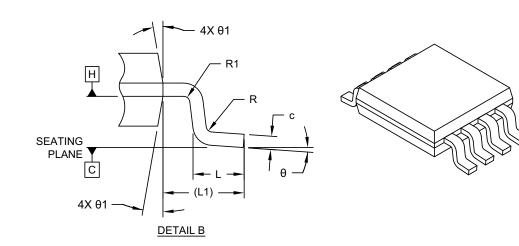
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-111-MS Rev F Sheet 1 of 2

8-Lead Plastic Micro Small Outline Package (MS) - 3x3 mm Body [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dime	ension Limits	MIN	NOM	MAX
Number of Terminals	N		8	
Pitch	е		0.65 BSC	
Overall Height	A	-	-	1.10
Standoff	A1	0.00	-	0.15
Molded Package Thickness	A2	0.75	0.85	0.95
Overall Length		3.00 BSC		
Overall Width	E	4.90 BSC		
Molded Package Width	E1	3.00 BSC		
Terminal Width	b	0.22	-	0.40
Terminal Thickness	С	0.08	-	0.23
Terminal Length	L	0.40	0.60	0.80
Footprint	L1	0.95 REF		
Lead Bend Radius	R	0.07	-	-
Lead Bend Radius	R1	0.07	-	_
Foot Angle	θ	0°	-	8°
Mold Draft Angle	θ1	5°	-	15°

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

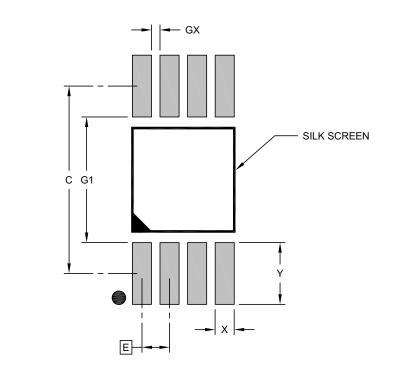
2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or

protrusions shall not exceed 0.15mm per side. 3. Dimensioning and tolerancing per ASME Y14.5M BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-111-MS Rev F Sheet 2 of 2

8-Lead Plastic Micro Small Outline Package (MS) - 3x3 mm Body [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		N	ILLIMETER	S	
Dimension Limits		MIN	NOM	MAX	
Contact Pitch	Contact Pitch E		0.65 BSC		
Contact Pad Spacing	С	4.40			
Contact Pad Width (X8) X				0.45	
Contact Pad Length (X8) Y				1.45	
Contact Pad to Contact Pad (X4)	G1	2.95			
Contact Pad to Contact Pad (X6)	GX	0.20			

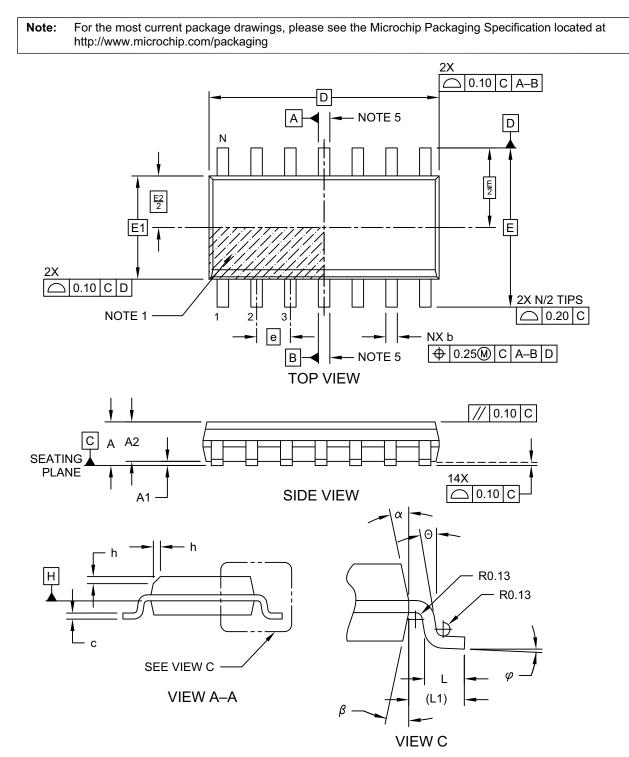
Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-2111-MS Rev F

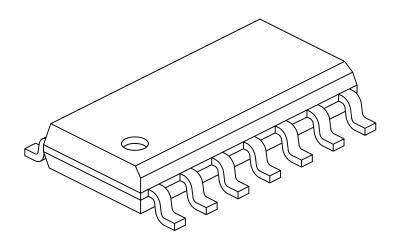
14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]



Microchip Technology Drawing No. C04-065-SL Rev D Sheet 1 of 2

14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimensior	Limits	MIN	NOM	MAX
Number of Pins N			14	
Pitch	е		1.27 BSC	
Overall Height	Α	-	-	1.75
Molded Package Thickness	A2	1.25	-	-
Standoff §	A1	0.10	-	0.25
Overall Width	E	6.00 BSC		
Molded Package Width	h E1 3.90 BSC			
Overall Length	D		8.65 BSC	
Chamfer (Optional)	h	0.25	-	0.50
Foot Length	L	0.40	-	1.27
Footprint	L1		1.04 REF	
Lead Angle	Θ	0°	-	-
Foot Angle	φ	0°	-	8°
Lead Thickness	С	0.10	-	0.25
Lead Width	b	0.31	-	0.51
Mold Draft Angle Top	α	5°	-	15°
Mold Draft Angle Bottom	β	5°	-	15°

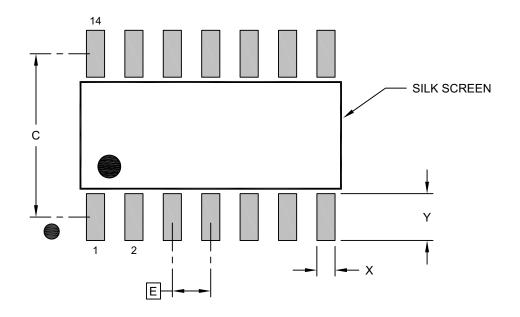
Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimension D does not include mold flash, protrusions or gate burrs, which shall not exceed 0.15 mm per end. Dimension E1 does not include interlead flash or protrusion, which shall not exceed 0.25 mm per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.
- REF. Reference Dimension, usually without tolerance, for information
- 5. Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-065-SL Rev D Sheet 2 of 2

14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		1.27 BSC	
Contact Pad Spacing	С		5.40	
Contact Pad Width (X14)	Х			0.60
Contact Pad Length (X14)	Y			1.55

Notes:

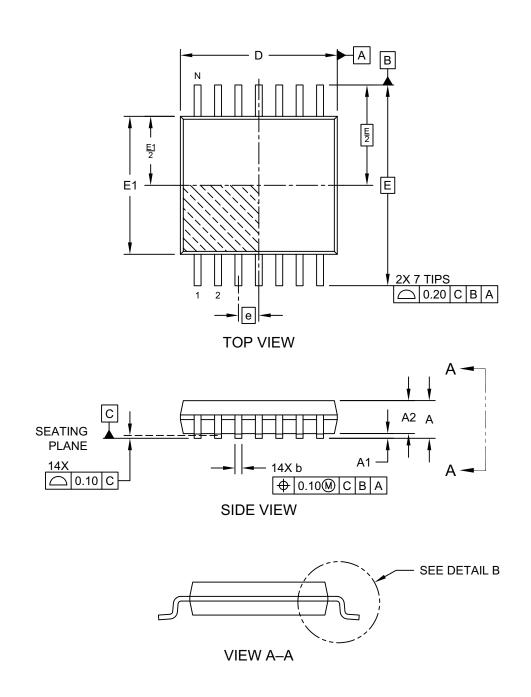
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2065-SL Rev D

14-Lead Thin Shrink Small Outline Package [ST] – 4.4 mm Body [TSSOP]

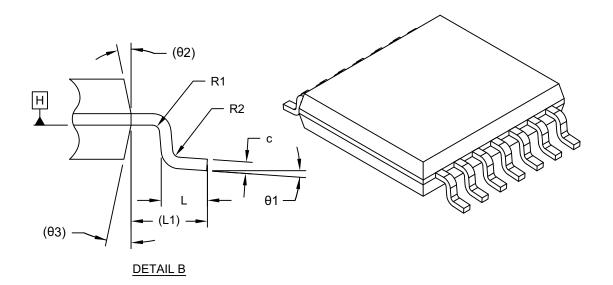
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-087 Rev E Sheet 1 of 2

14-Lead Thin Shrink Small Outline Package [ST] – 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimens	ion Limits	MIN	NOM	MAX
Number of Terminals	N		14	
Pitch	е		0.65 BSC	
Overall Height	А	-	-	1.20
Standoff	A1	0.05	_	0.15
Molded Package Thickness	A2	0.80	1.00	1.05
Overall Length	D	4.90	5.00	5.10
Overall Width	E	6.40 BSC		
Molded Package Width	E1	4.30	4.40	4.50
Terminal Width	b	0.19	-	0.30
Terminal Thickness	С	0.09	-	0.20
Terminal Length	L	0.45	0.60	0.75
Footprint	L1		1.00 REF	
Lead Bend Radius	R1	0.09	-	-
Lead Bend Radius	R2	0.09	-	-
Foot Angle	θ1	0°	_	8°
Mold Draft Angle	θ2	_	12° REF	_
Mold Draft Angle	θ3	_	12° REF	_

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

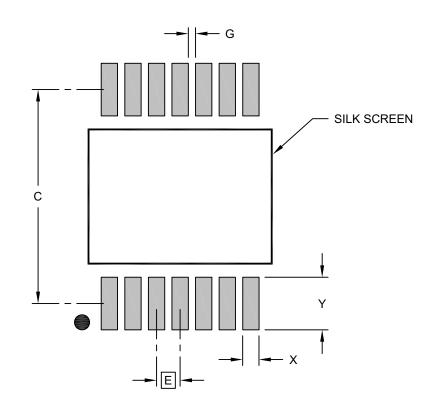
- 2. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-087 Rev E Sheet 2 of 2

14-Lead Thin Shrink Small Outline Package [ST] – 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension	Dimension Limits		NOM	MAX
Contact Pitch	Е	E 0.65 BSC		
Contact Pad Spacing	С		5.90	
Contact Pad Width (Xnn)	Х			0.45
Contact Pad Length (Xnn)	Y			1.45
Contact Pad to Contact Pad (Xnn)	G	0.20		

Notes:

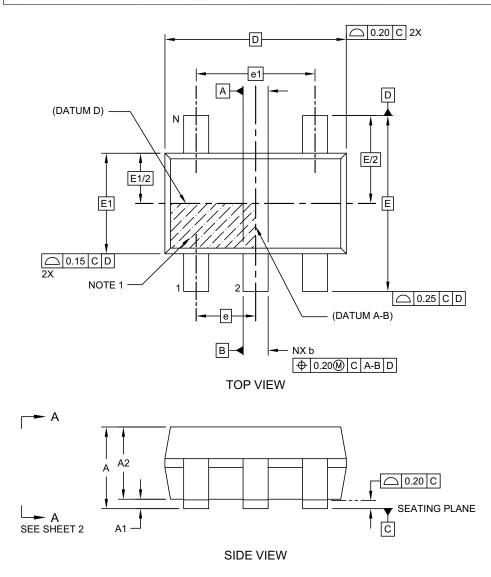
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-2087 Rev E

5-Lead Plastic Small Outline Transistor (OT) [SOT-23]

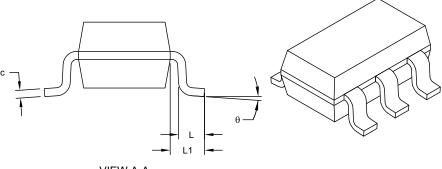
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-091-OT Rev H Sheet 1 of 2

5-Lead Plastic Small Outline Transistor (OT) [SOT-23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





	MILLIMETERS				
Dimension	Limits	MIN	NOM	MAX	
Number of Pins	Ν		5		
Pitch	е		0.95 BSC		
Outside lead pitch	e1		1.90 BSC		
Overall Height	Α	0.90	-	1.45	
Molded Package Thickness	A2	0.89	-	1.30	
Standoff	A1	-	-	0.15	
Overall Width	E		2.80 BSC		
Molded Package Width	E1		1.60 BSC		
Overall Length	D		2.90 BSC		
Foot Length	L	0.30	-	0.60	
Footprint	L1		0.60 REF		
Foot Angle	θ	0°	-	10°	
Lead Thickness	С	0.08	-	0.26	
Lead Width	b	0.20	-	0.51	

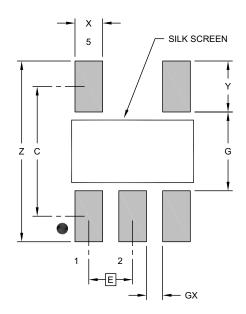
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.25mm per side.
 Dimensioning and tolerancing per ASME Y14.5M BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-091-OT Rev H Sheet 2 of 2

5-Lead Plastic Small Outline Transistor (OT) [SOT-23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units	MILLIMETERS			
Dimension	Limits	MIN NOM 0.95 BSC 2.80		MAX	
Contact Pitch	Е		0.95 BSC		
Contact Pad Spacing	С		2.80		
Contact Pad Width (X5)	Х			0.60	
Contact Pad Length (X5)	Y			1.10	
Distance Between Pads	G	1.70			
Distance Between Pads	GX	0.35			
Overall Width	Z			3.90	

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2091-OT Rev H

NOTES:

APPENDIX A: REVISION HISTORY

Revision B (March 2023)

The following is a list of modifications and corrections:

- Corrected title for Figure 2-8.
- Added packaging information for MCP6489-E/ST and MCP6489T-E/ST in Product Identification System.
- Added section Product Identification System (Automotive).

Revision A (May 2022)

• Original release of this document.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.+

PART NO.	<u>×</u> (1)	<u>-X</u>	<u>/XX</u>	<u>xxx⁽²⁾</u>	Exa	mples:	
Device	 Tape and F Option	 Reel Temperature Range	Package	CLASS	a)	MCP6486T-E/LT:	Tape and Reel, Extended temperature, 5LD SC-70 package
Device:	MCP6486 MCP6486T	Single Op Amp Single Op Amp (Tape (SC-70, SOT-23)	e and Reel)		b)	MCP6486T-E/OT:	Tape and Reel, Extended temperature, 5LD SOT-23 package
	MCP6486RT MCP6486UT	Single Op Amp (Tape Single Op Amp (Tape (SC-70, SOT-23)	, ,	SOT-23)	c)	MCP6486RT-E/OT:	Tape and Reel, Extended temperature, 5LD SOT-23 package
	MCP6487 MCP6487T	Dual Op Amp Dual Op Amp			d)	MCP6486UT-E/LT:	Tape and Reel, Extended temperature, 5LD SC-70 package
	MCP6489 MCP6489T	(Tape and Reel for S Quad Op Amp Quad Op Amp	,		e)	MCP6486UT-E/OT:	Tape and Reel, Extended temperature, 5LD SOT-23 package
Temperatu	ire Range: E =	(Tape and Reel for Tape -40°C to +125°C	SSOP and SC	JIC)	a)	MCP6487-E/SN:	Extended temperature, 8LD SOIC package
•		Package (SC-70), 5-le		• •	b)	MCP6487-E/MS:	Extended temperature, 8LD MSOP package
	(MCP64	Small Outline transistc 486 only) Small Outline, (3.90 m	, , , , , , , , , , , , , , , , , , ,		c)	MCP6487T-E/SN:	Tape and Reel, Extended temperature, 8LD SOIC package
	ST = Plastic	MSOP, 8-lead MCP64 Thin Shrink Small Out 189 only)	.,	, 14-Lead,	d)	MCP6487T-E/MS:	Tape and Reel, Extended temperature, 8LD MSOP package
	SL = Plastic \$ Blank)= Non-Au	Small Outline, (3.90 m tomotive	m), 14-Lead	(MCP6489 only)	a)	MCP6489-E/ST:	Extended temperature, 14LD TSSOP package
N	/AO = Automot	ive			b)	MCP6489-E/SL:	Extended temperature, 14LD SOIC package
Note 1:	number descri	I Reel identifier only iption. This identifier i	s used for or	dering purposes		MCP6489T-E/ST:	Tape and Reel, Extended temperature, 14LD TSSOP package
		inted on the device es Office for package		,	u)	MCP6489T-E/SL:	Tape and Reel, Extended temperature, 14LD SOIC package
2:	Automotive pa	arts are AEC-Q100 q	ualified. Grad	de 1.			

PRODUCT IDENTIFICATION SYSTEM (AUTOMOTIVE)

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	<mark>×(1</mark>)	<u>-X</u>	<u>/XX</u>	<u>xxx⁽²⁾</u>	Exa	mples:	
Device		Reel Temperature Range	Package	CLASS	a)	MCP6486T-E/LTVAO:	Automotive, Extended temperature,
Device:	MCP6486 MCP6486T MCP6486RT	Single Op Amp Single Op Amp (Tape (SC-70, SOT-23)	,	SOT 22)	b)	MCP6486T-E/OTVAC	5LD SC-70 package Tape and Reel, Automotive, Extended temperature,
	MCP6486UT MCP6487 MCP6487T	Single Op Amp (Tape Single Op Amp (Tape (SC-70, SOT-23) Dual Op Amp Dual Op Amp	, ,	501-23)	c)	MCP6486RT-E/OTVA	5LD SOT-23 package O:Tape and Reel, Automotive, Extended temperature, 5LD SOT-23 package
	MCP6489 MCP6489T	(Tape and Reel for Se Quad Op Amp Quad Op Amp			d)	MCP6486UT-E/LTVA	
	-	(Tape and Reel for TS - 40°C to +125°C Package (SC-70), 5-le		,	e)	MCP6486UT-E/OTVA	O:Tape and Reel, Automotive, Extended temperature,
	OT = Plastic S (MCP64 SN = Plastic S	Small Outline transisto 186 only) Small Outline, (3.90 m	or (SOT-23), 5 m), 8-lead (N	i-Lead,	a)	MCP6487-E/SNVAO:	Extended temperature,
:	ST = Plastic 1 (MCP64	MSOP, 8-lead MCP64i Thin Shrink Small Outl 189 only) Small Outline, (3.90 m	ine (4.4 mm)		b)	MCP6487-E/MSVAO:	8LD SOIC package Automotive, Extended temperature, 8LD MSOP package
Class: (I	Blank)= Non-Aut /AO =Automoti	tomotive	,,	(, ,	c)	MCP6487T-E/SNVAC):Tape and Reel, Automotive, Extended temperature, 8LD SOIC package
Note 1:	The Tape and	Reel identifier only	appears in	the catalog part	d)	MCP6487T-E/MSVAC	D:Tape and Reel, Automotive, Extended temperature, 8LD MSOP package
	number description. This identifier is used for or and is not printed on the device package. O Microchip Sales Office for package availability w Reel option.	Check with your	a)	MCP6489-E/STVAO:	Automotive, Extended temperature, 14LD TSSOP package		
2:	•	arts are AEC-Q100 qเ	ualified. Grad	de 1.	b)	MCP6489-E/SLVAO:	Automotive, Extended temperature, 14LD SOIC package
					c)	MCP6489T-E/STVAC	Tape and Reel, Automotive, Extended temperature, 14LD TSSOP package
					d)	MCP6489T-E/SLVAO	Tape and Reel, Automotive, Extended temperature, 14LD SOIC package

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